

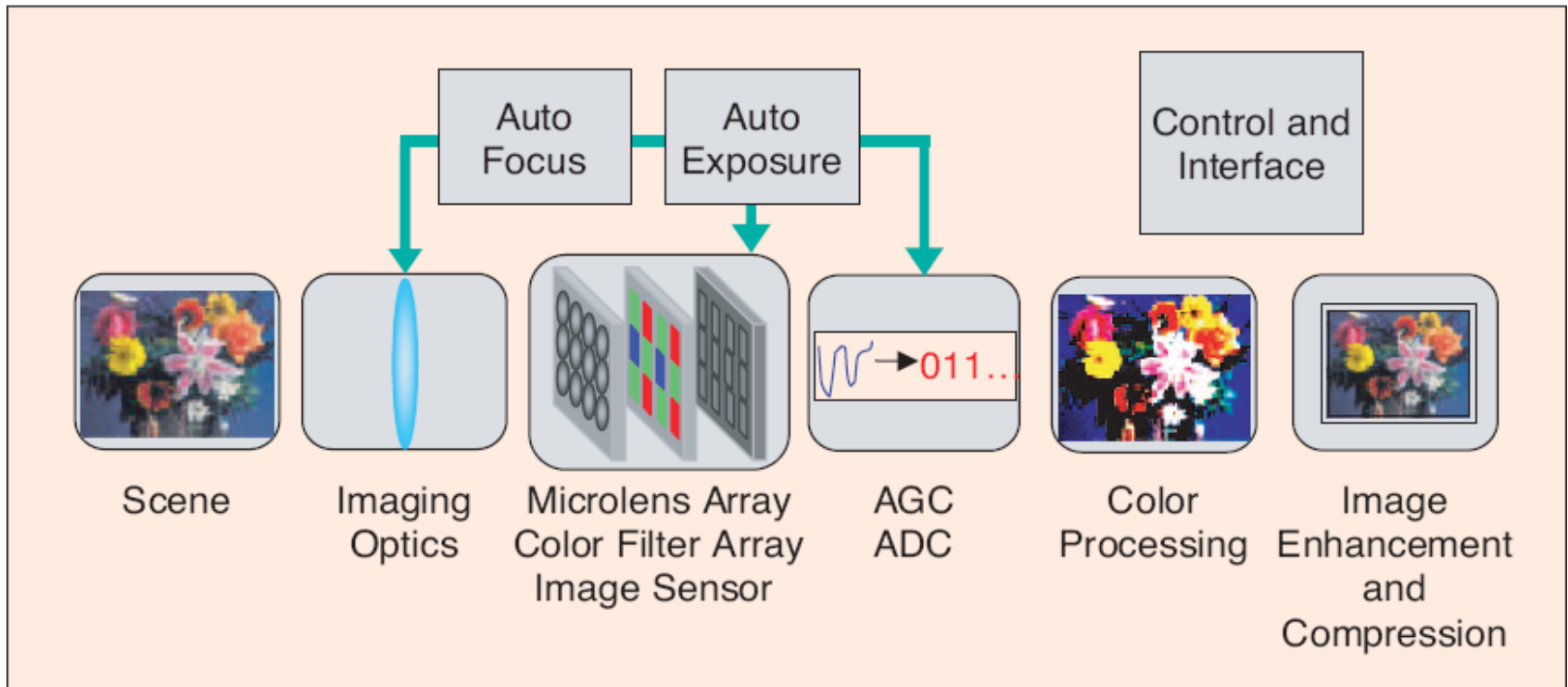
**UiO** : **Department of Informatics**  
University of Oslo

**INF5350/IN9350 – CMOS Image Sensor Design**

**Lecture 1 – Camera systems overview**

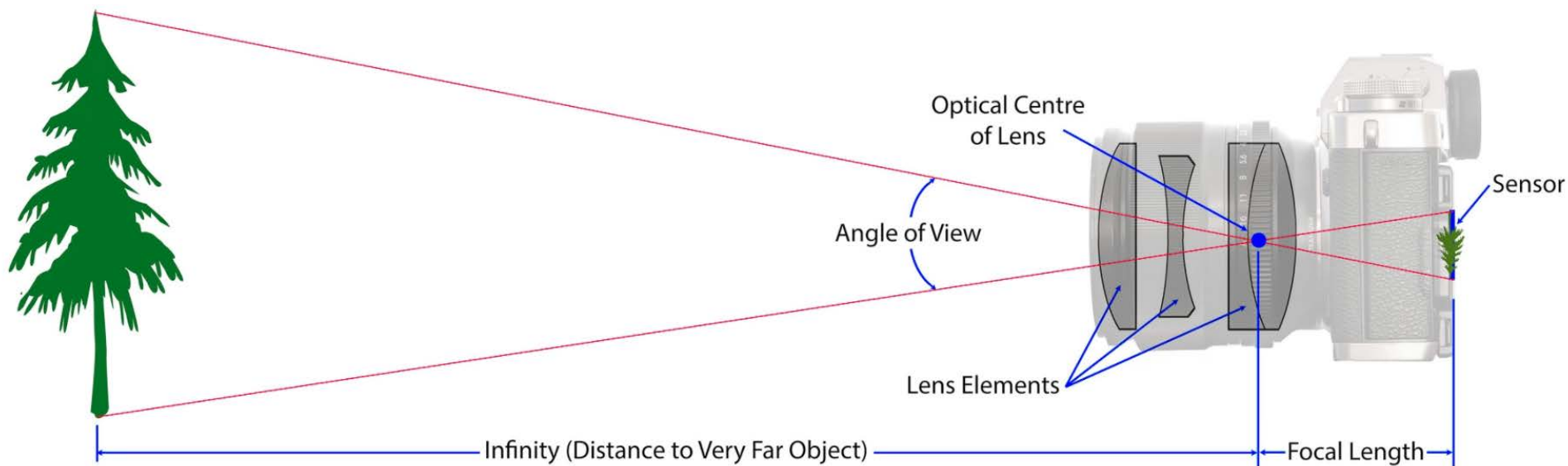


# CMOS camera signal chain



Source: A.E.Gamal, et al. "CMOS Image Sensors", IEEE Circuits and Device Magazine, May. 2005

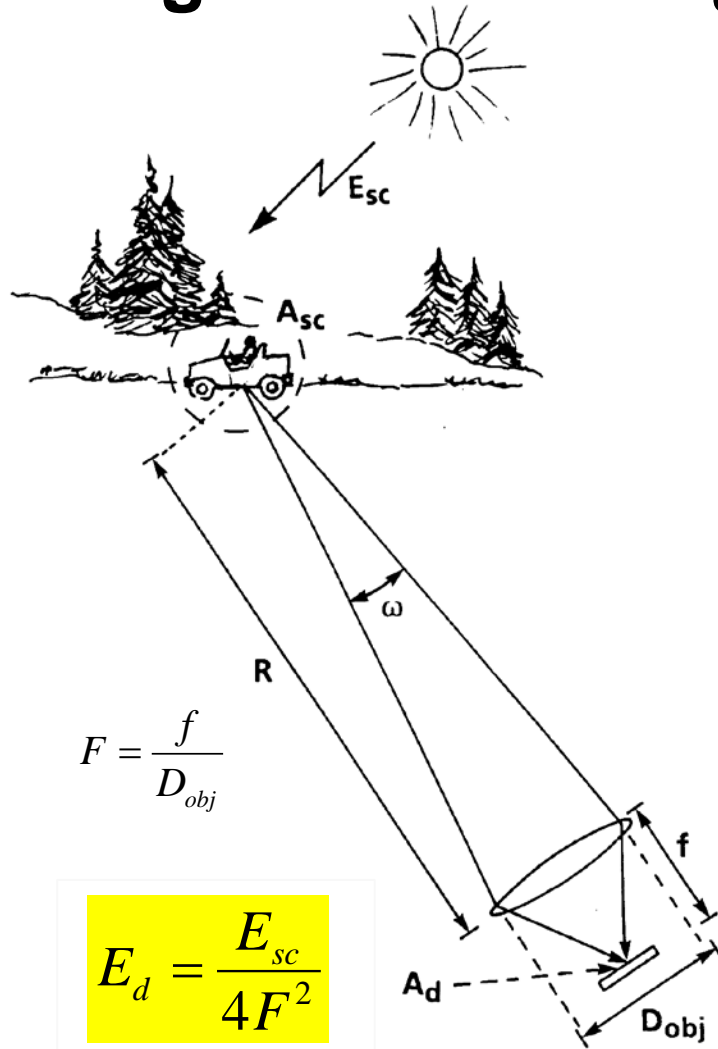
# Camera focal length and field of view



Focal length = distance from 'optical centre of lens' to focal point where image sensor chip is placed

Focal length + sensor size defines the angle of view (aka field of view)

# Light flux on image sensor chip



$E_{sc}$ =scene illumination (lux or W/m<sup>2</sup>)

$\rho_{sc}$ =scene reflectivity (no unit)

$T_{int}$ =camera exposure time (s)

$F$ =lense F-nummer ( $=f/D_{obj}$ )

$h$ =Plancks constant ( $6.6 \times 10^{-34}$  J s)

$c$ =speed of light ( $3 \times 10^8$  m/s)

$D_{obj}$ = lens aperture (m)

$f$  = lens focal length (m)

$A_d$ =detector area (m<sup>2</sup>)

$E_d$ =detector illumination (lux or W/m<sup>2</sup>)

$\lambda$ =light spectral wavelength (m)

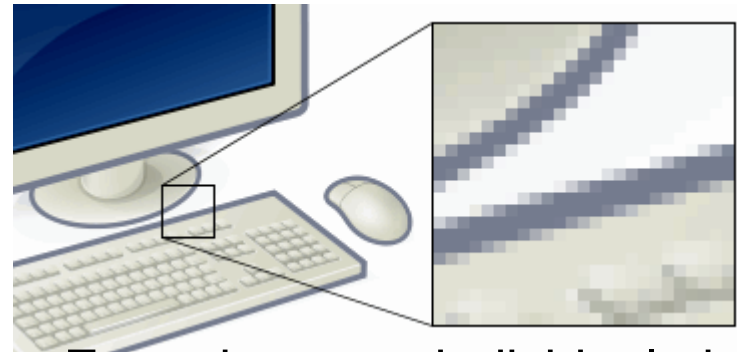
$S_d$ =detector photon count (no unit)

$$S_d = \frac{T_{int} A_d}{hc 4 F^2} E_{sc} \rho_{sc}$$

# Digital picture

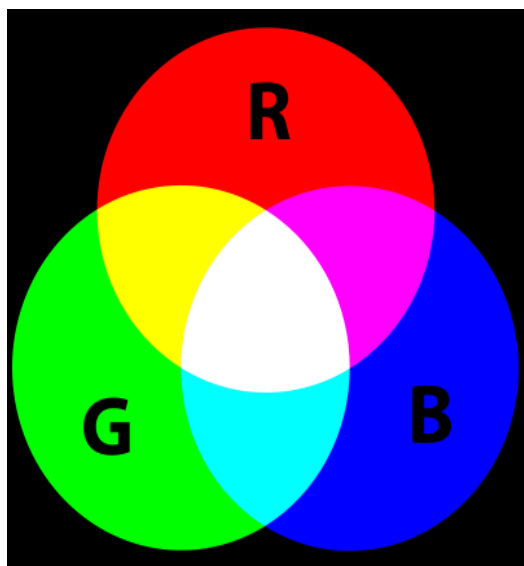
- Consists of 2D array of pixels each containing three numbers (R+G+B or Y+U+V) to describe the pixel color and its brightness (luminous intensity)

Zoom-in on LCD monitor w/RGB pixels

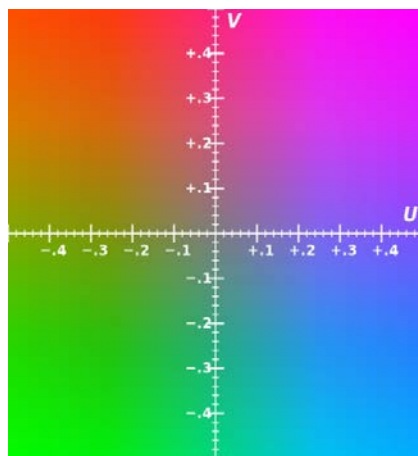


Zoom-in to see individual pixel elements

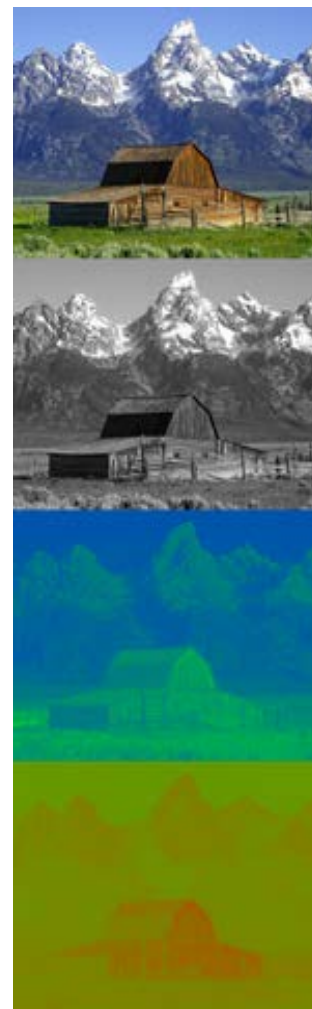
# RGB vs YUV



Mixing primary colors  
(RGB)



U-V color plane  
(Y=0.5)



YUV image  
along with its

Y,

U, and


V components.


# From RGB to YUV, and vice-versa

$$Y' = 0.299R + 0.587G + 0.114B$$

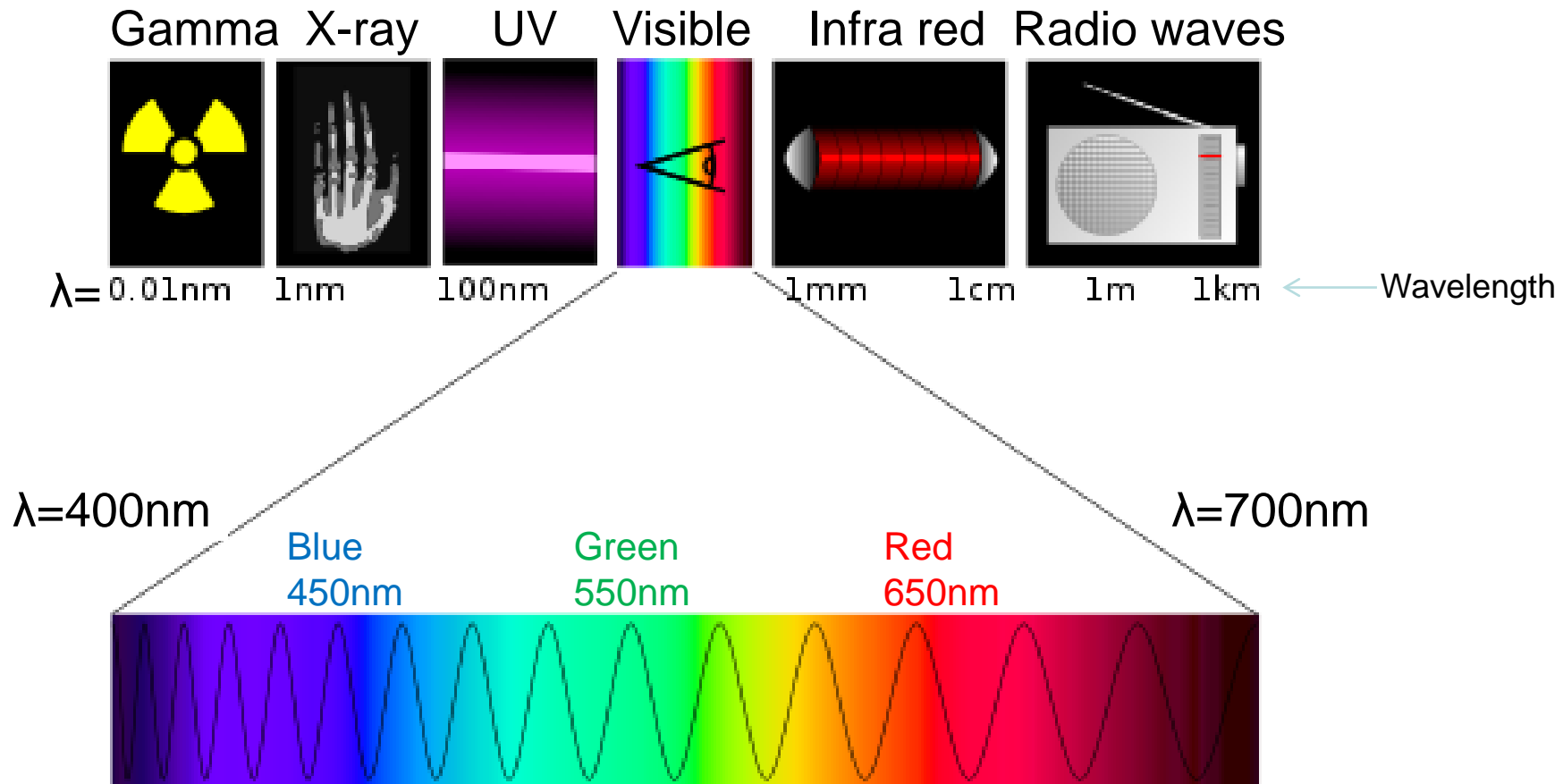
$$U = 0.492(B - Y')$$

$$V = 0.877(R - Y')$$

 
$$\begin{bmatrix} Y \\ U \\ V \end{bmatrix} = \begin{bmatrix} 0.2988 & 0.5869 & 0.1143 \\ -0.1689 & -0.3311 & 0.5000 \\ 0.5000 & -0.4189 & -0.0811 \end{bmatrix} \begin{bmatrix} R \\ G \\ B \end{bmatrix}$$

 
$$\begin{bmatrix} R \\ G \\ B \end{bmatrix} = \begin{bmatrix} 1 & 0 & 1.402 \\ 1 & -0.3441 & -0.7141 \\ 1 & 1.772 & 0.00015 \end{bmatrix} \begin{bmatrix} Y \\ U \\ V \end{bmatrix}$$

# Electromagnetic Spectrum

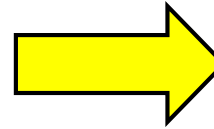
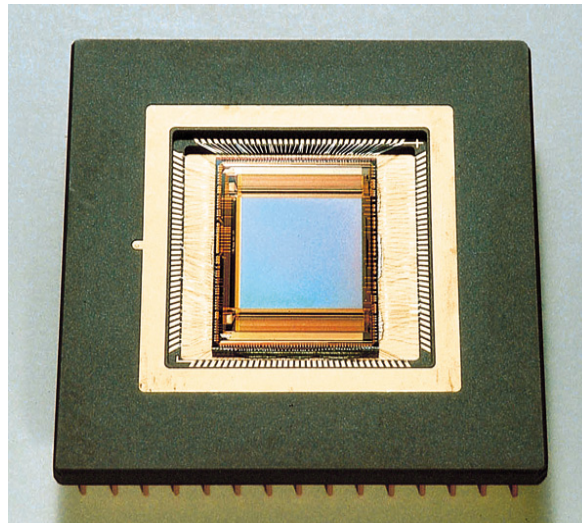
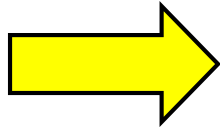




# From light in to digital pictures out

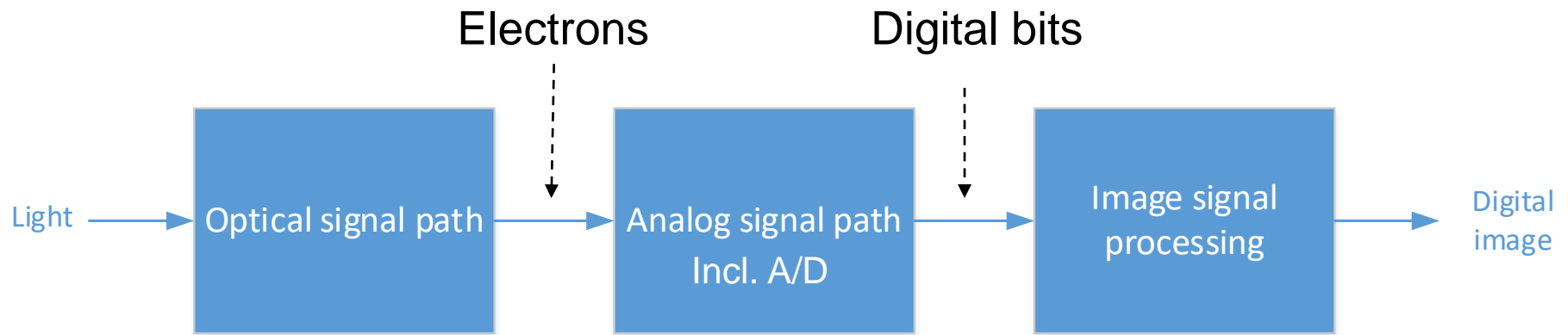
CMOS image sensor chip

**Light**

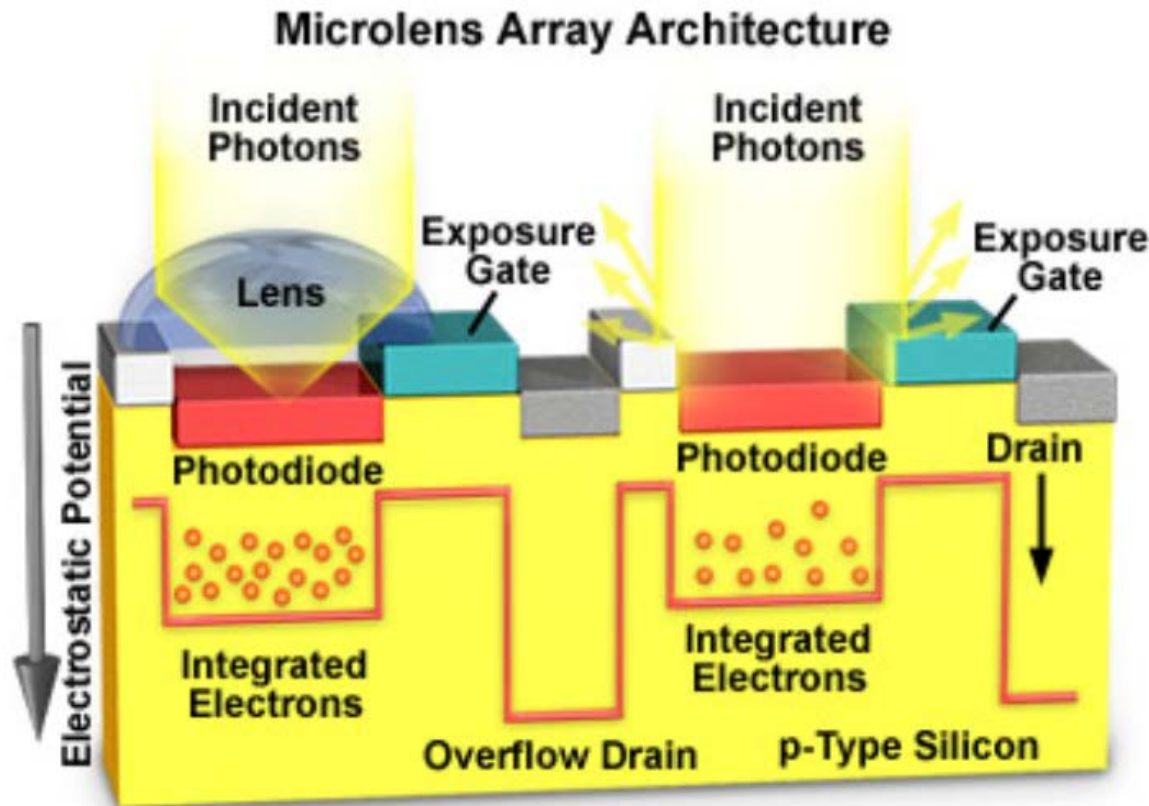


**Digital  
pictures**

# CMOS image sensor signal chain

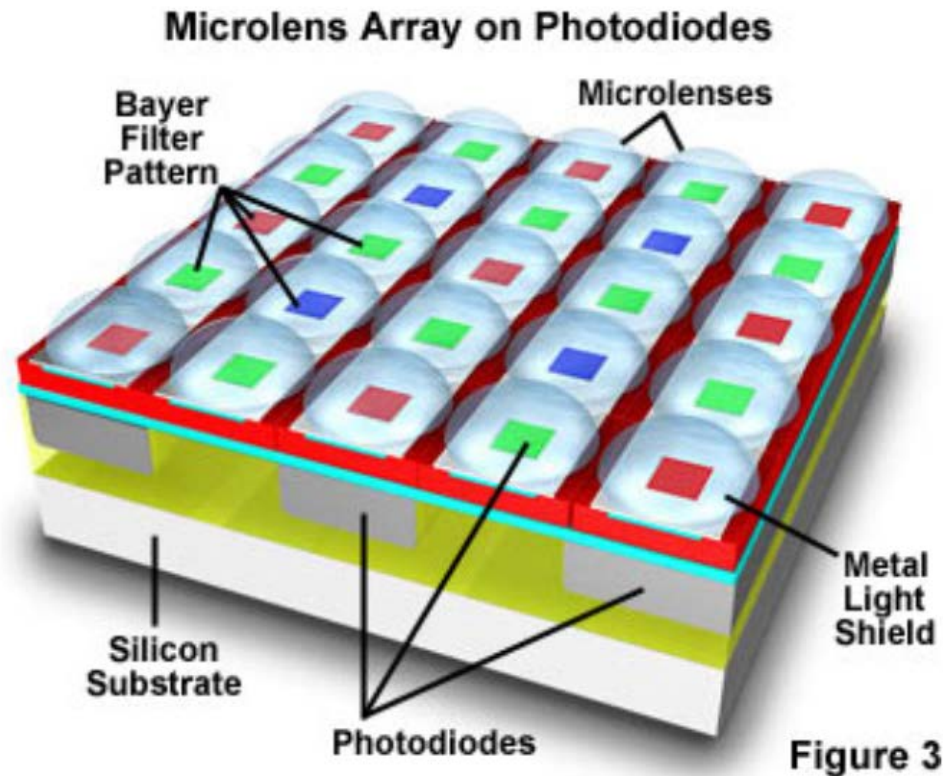


# Microlenses enhance light sensitivity



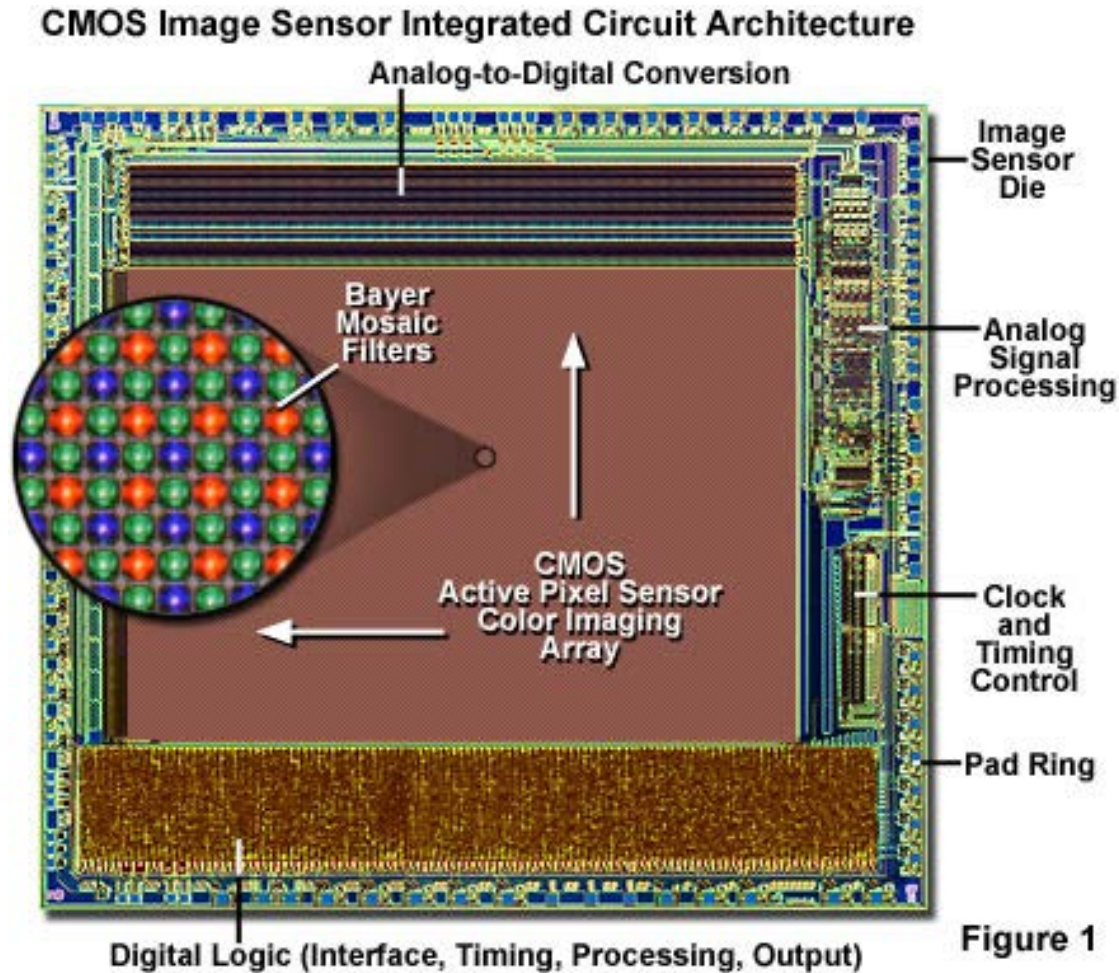
- Source: Hamamatsu

# Microlenses enhance light sensitivity



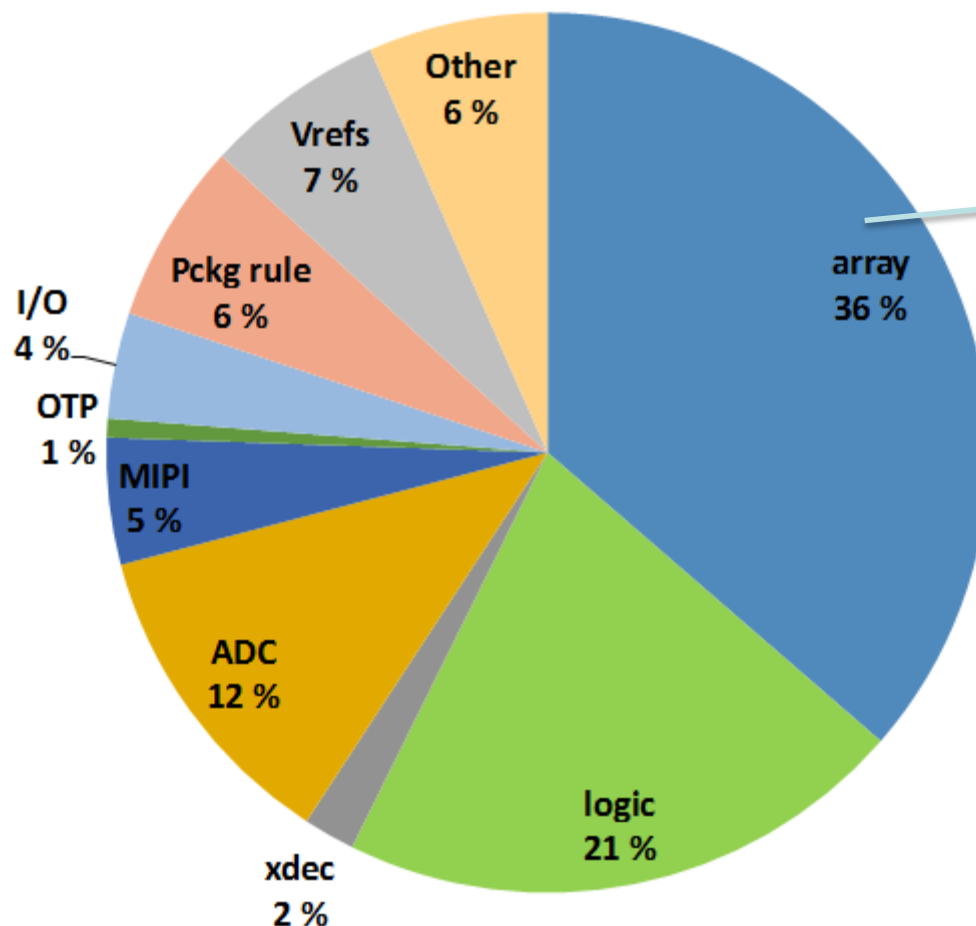
- Source: Hamamatsu

# CIS chip floorplan

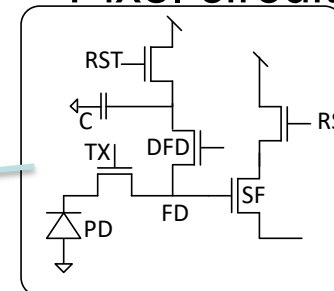


<http://www.olympusmicro.com/primer/digitalimaging/cmosimagesensors.html>

# Chip area breakdown (example)

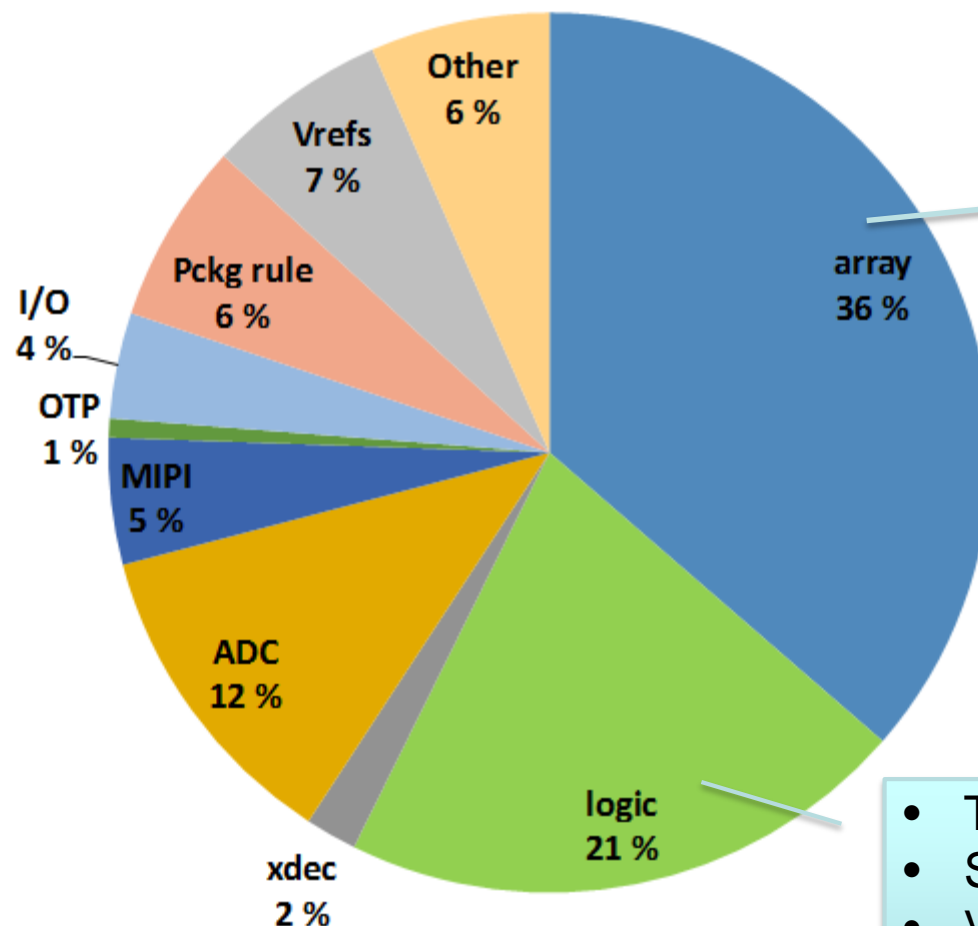


Pixel circuit

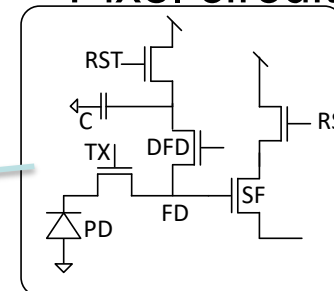




# Chip area breakdown (example)



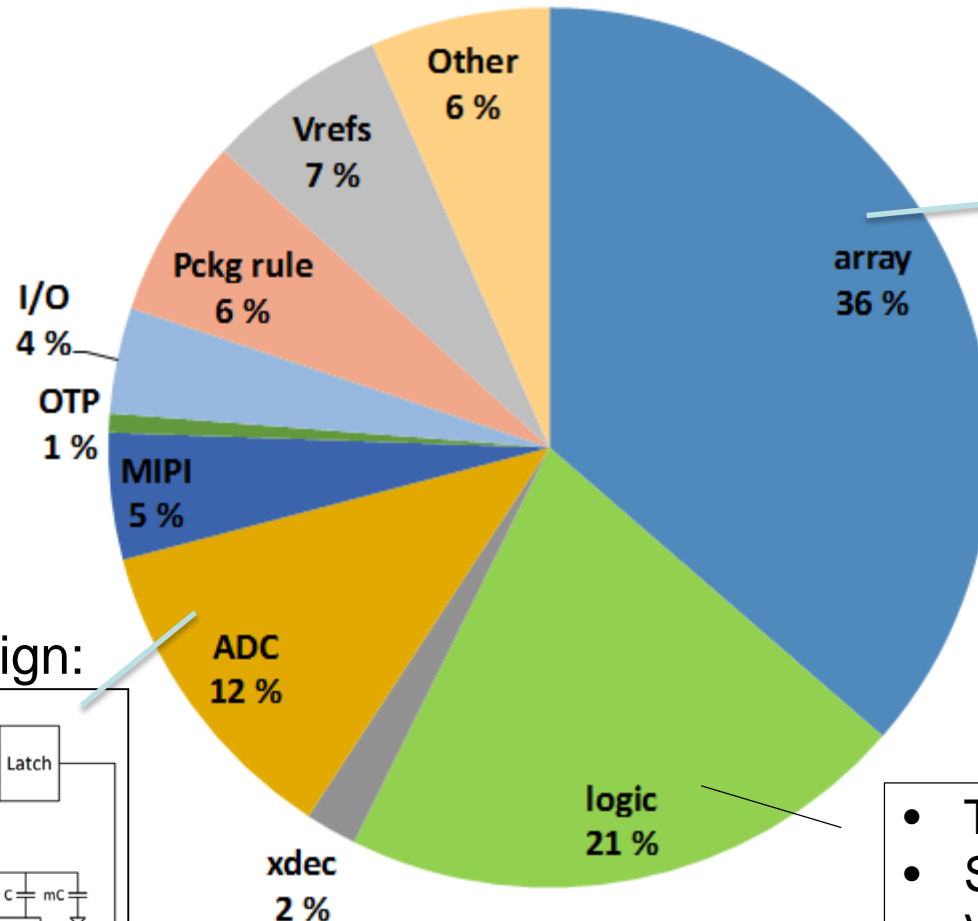
Pixel circuit



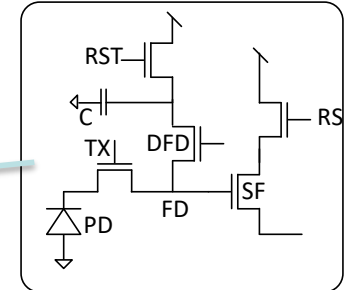
Digital design:

- Timing&Ctrl
- Signal processing
- Verilog RTL code
- FPGA emulation

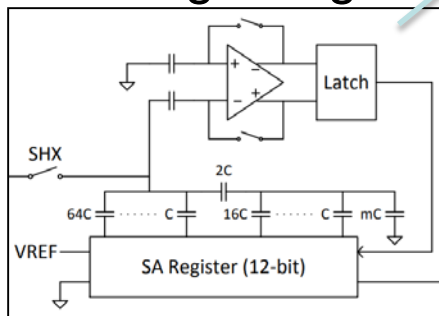
# Chip area breakdown (example)



Pixel circuit



Analog design:



Digital design:

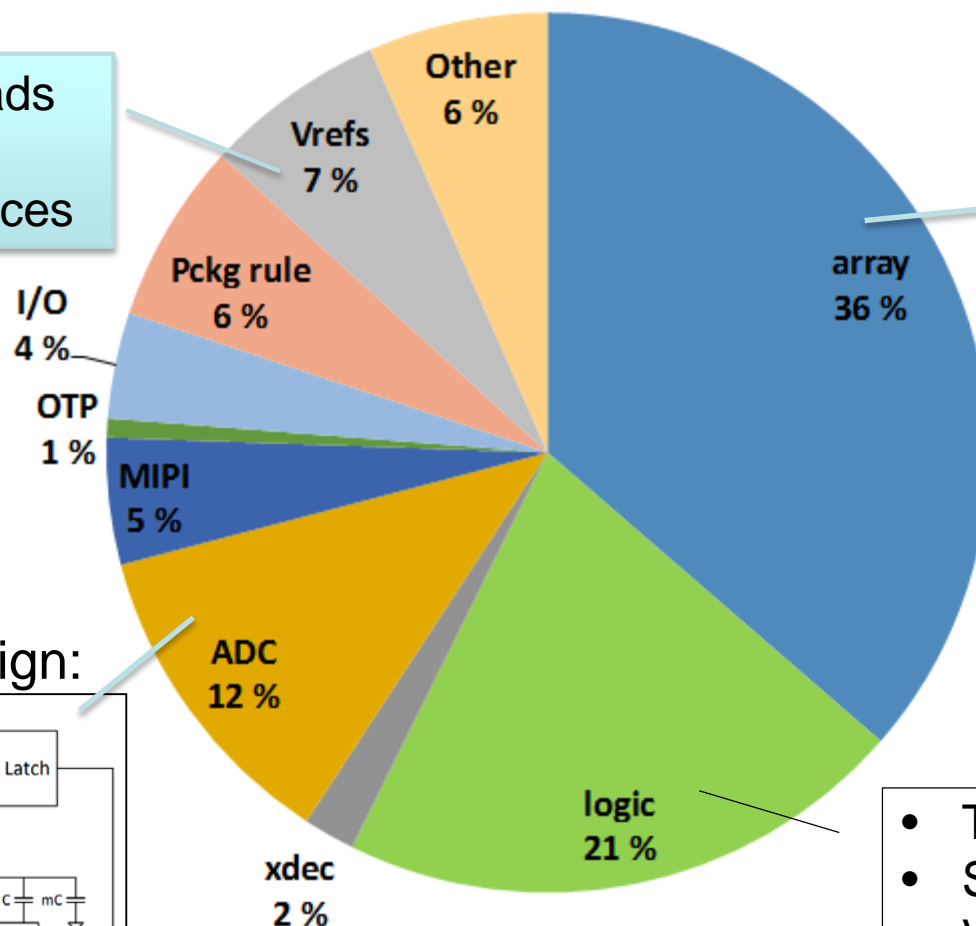
- Timing&Ctrl
- Signal processing
- Verilog RTL code
- FPGA emulation



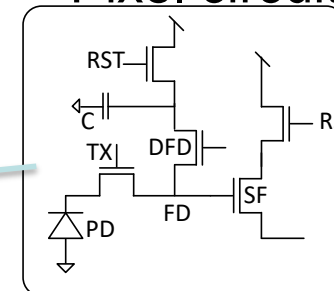
# Chip area breakdown (example)

## IP modules:

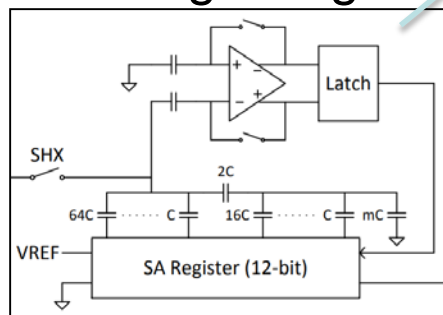
- Input/Output pads
- Serial interface
- Voltage references



## Pixel circuit



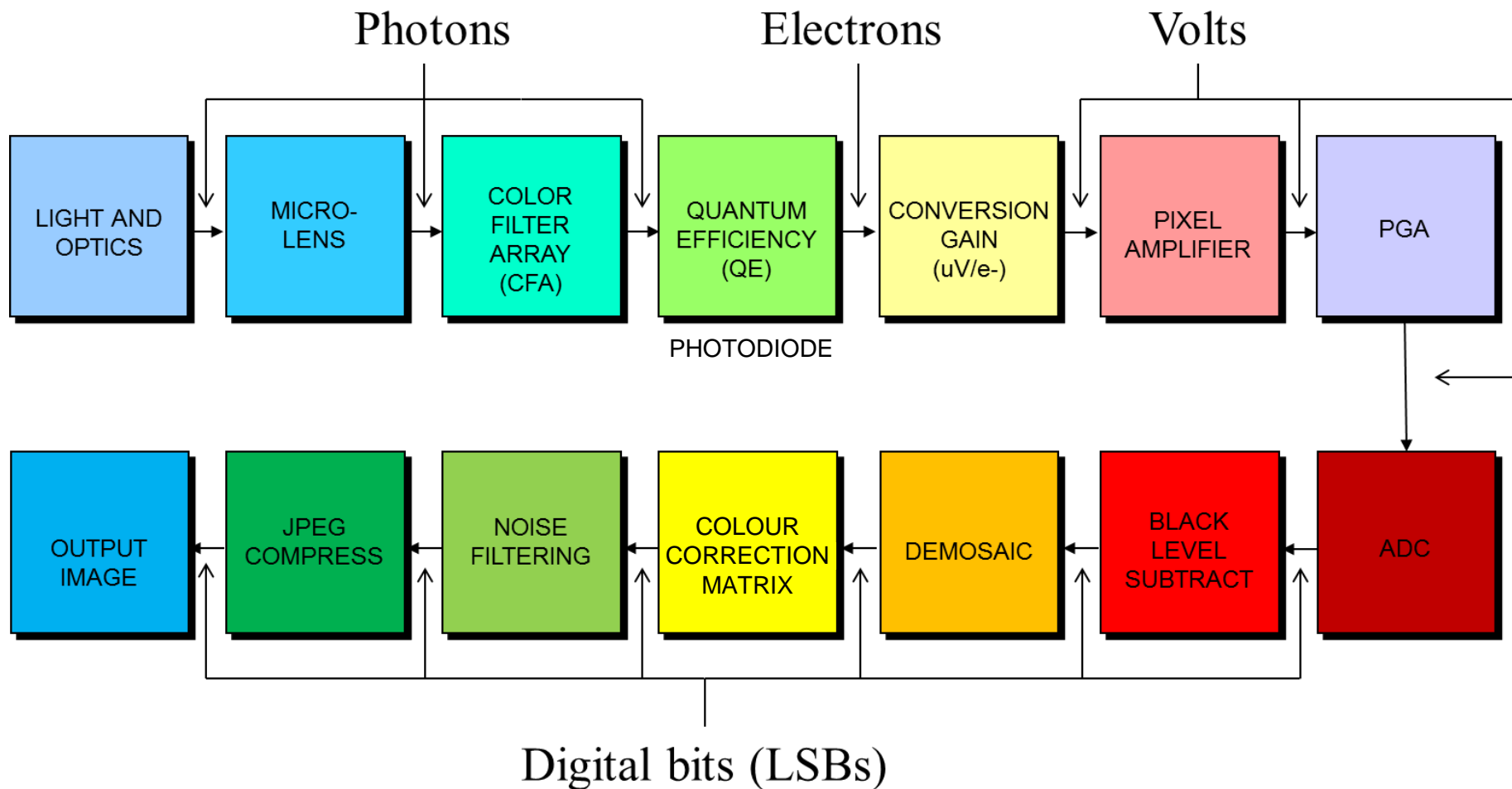
## Analog design:



## Digital design:

- Timing&Ctrl
- Signal processing
- Verilog RTL code
- FPGA emulation

# Digital camera signal chain



# CIS evaluation HW and SW

- Used for design validation/debug, image capture and performance measurements



Not shown: FPGA board + USB interface to PC

# Signal, Noise and Dynamic Range

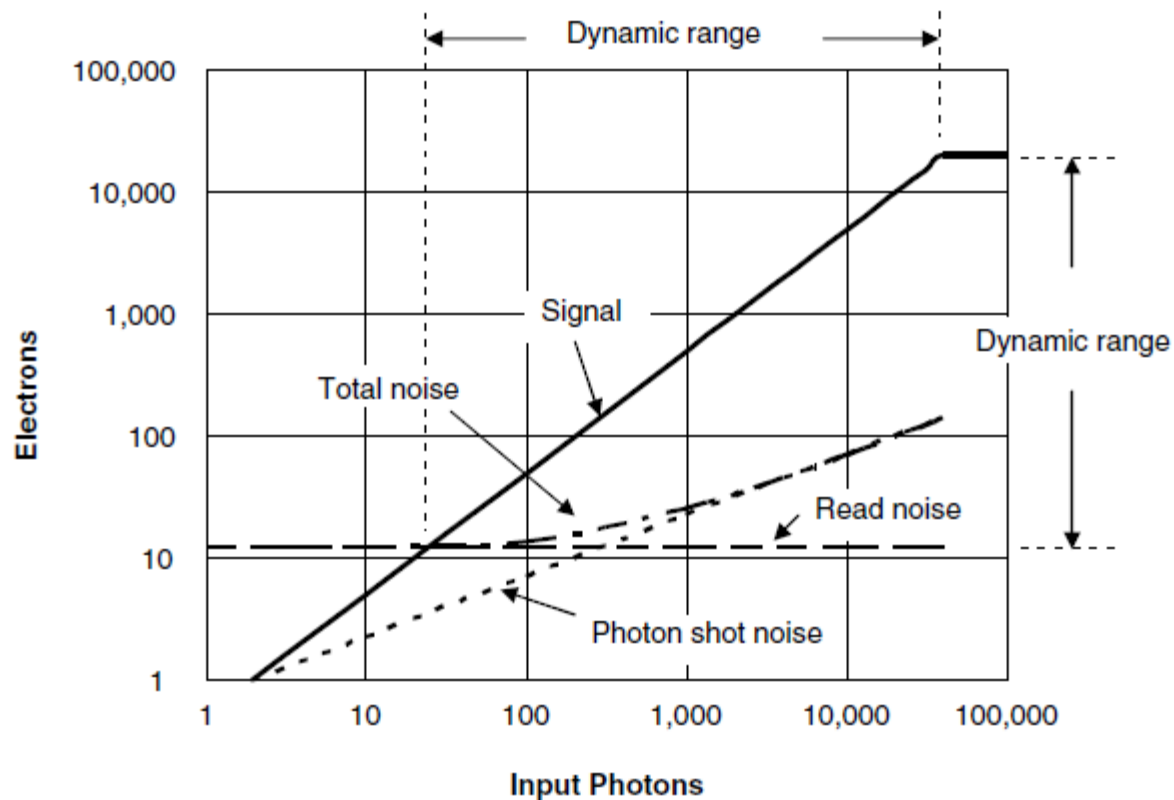


FIGURE 3.19 Example of photoconversion characteristics.  $A_{pix} = 25 \mu\text{m}^2$ ; C.G. =  $40 \mu\text{V}/e^-$ ,  $N_{sat} = 20,000 e^-$ ,  $n_{read} = 12 e^-$ .

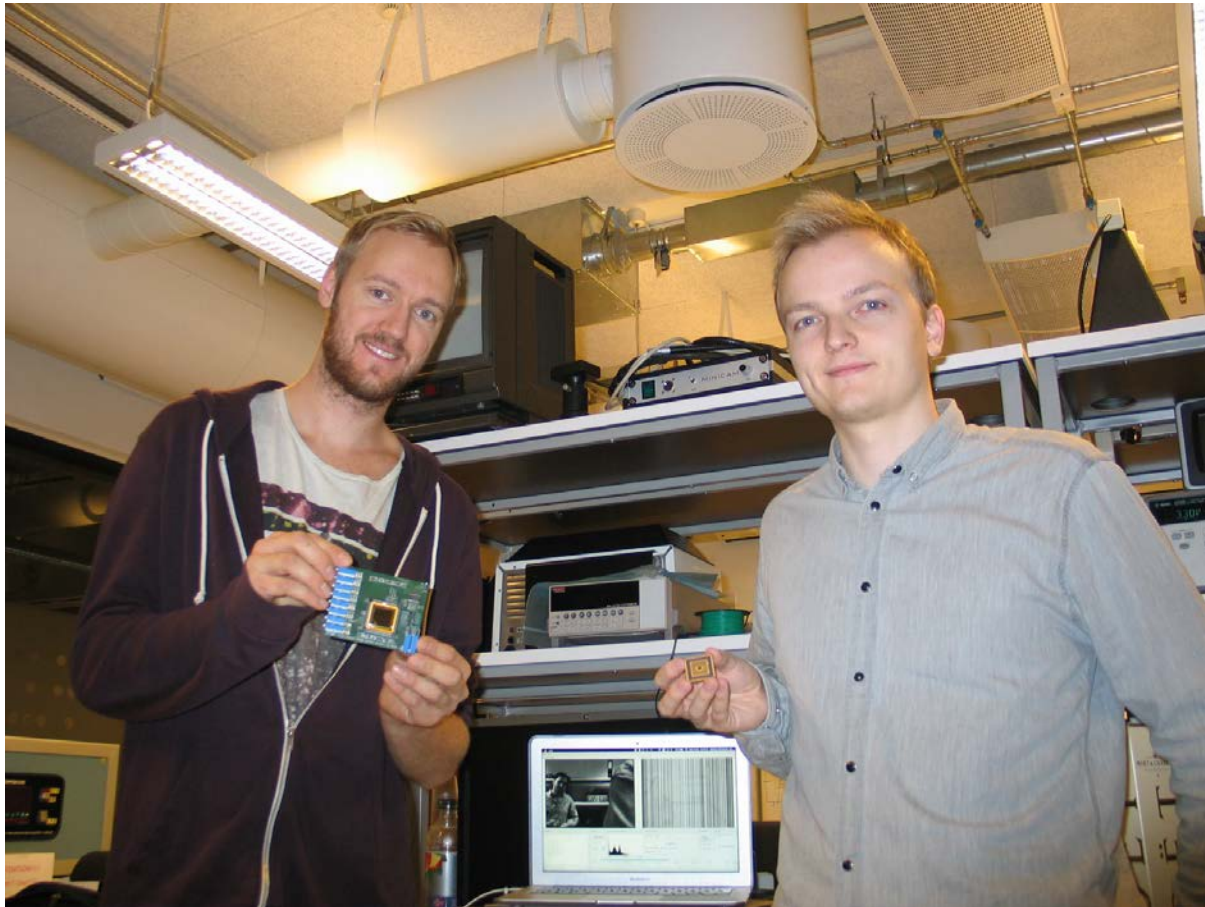
Source: Nakamura et.al.

## MSc project: CMOS camera-on-a-chip





# MSc project: CIS design and characterization



# APPLICATIONS AND TRENDS



Automotive camera  
(20bits/pixel)

Security camera  
(low light,  $<0.1\text{lux}$ )



Phone camera  
(small size,  $<5\text{mm}$ )



Machine vision  
(high-speed, 1000Hz)

## CMOS image sensor applications



Pill camera  
(low power,  $<10\text{mW}$ )



Digital still camera  
(high resolution,  $>20\text{Mpixels}$ )  
24



# High Dynamic Range Imaging

- The dynamic range of the typical scene is usually greater than the dynamic range a sensor can capture in one frame

HDR techniques enable better image quality by combining multiple captures into one image



Combined HDR image

HDR images contain more scene information

Non-HDR

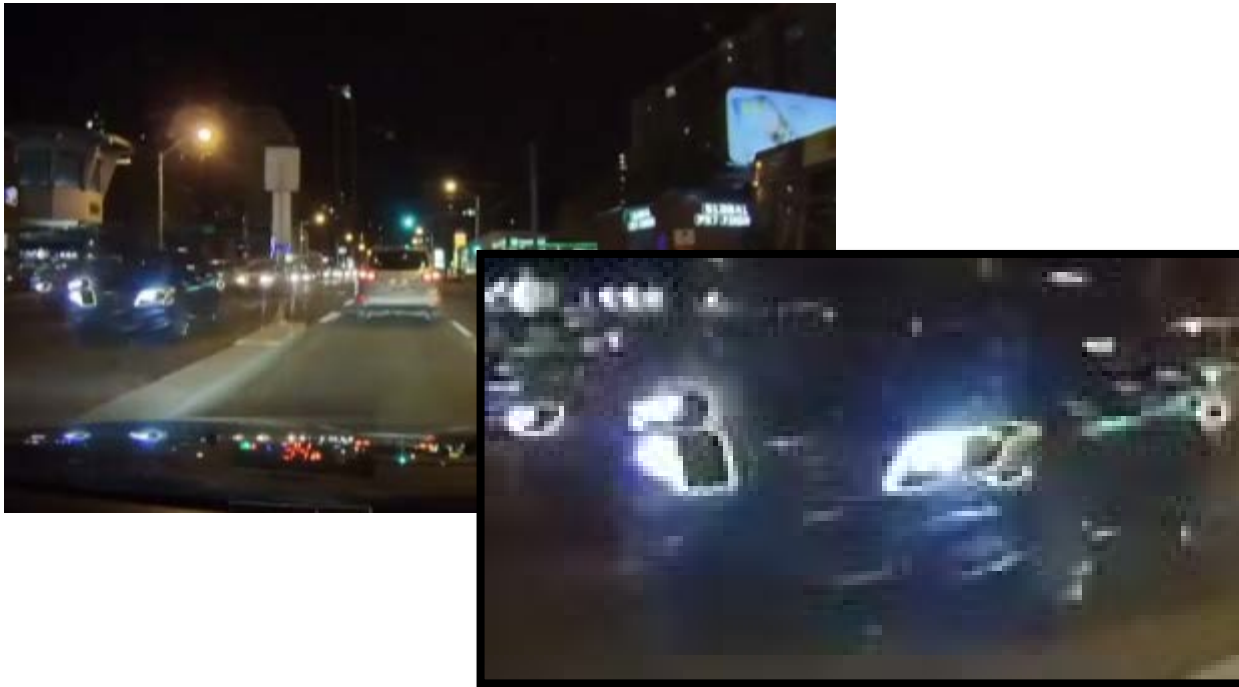


HDR

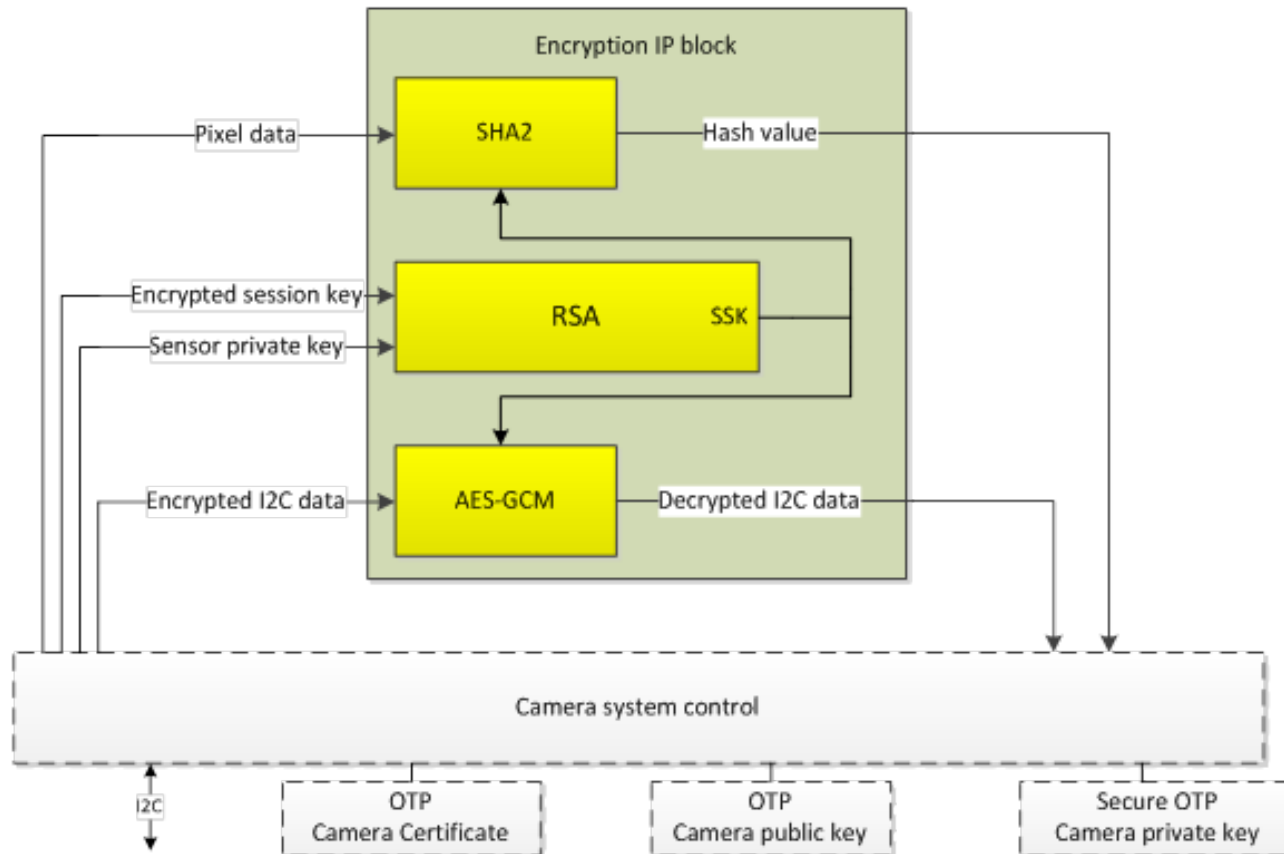


# HDR Motion Artifacts

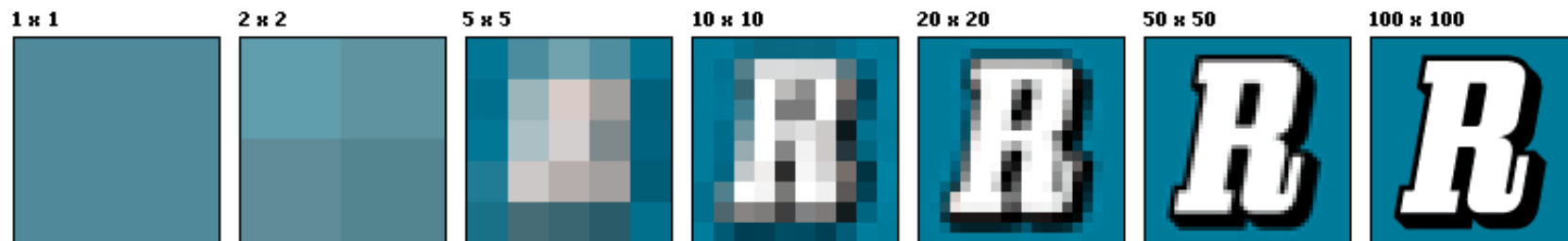
- Multi-capture HDR scheme introduces motion artifacts (“ghosting”) due to motion in scene, as objects are in different position for each capture



# RnD - Encryption in CMOS image sensors



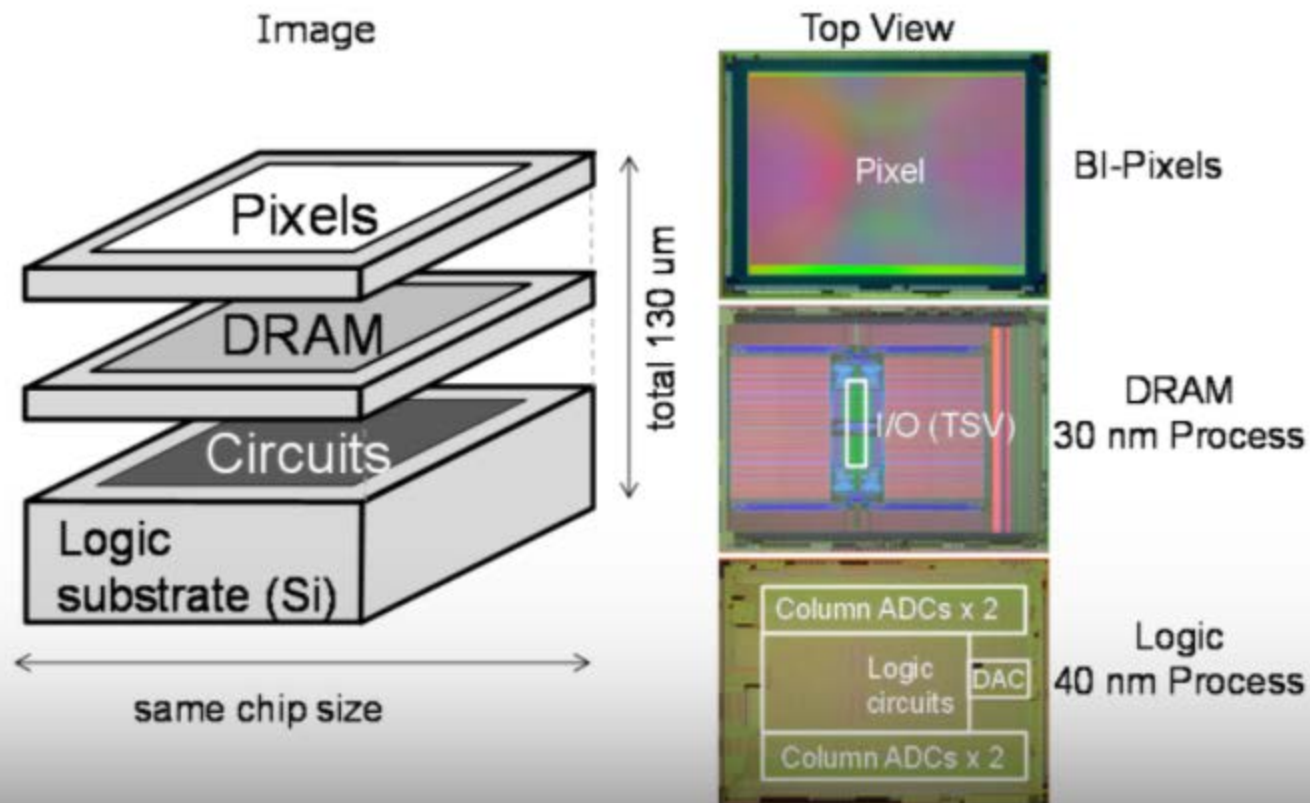
# More pixels give better resolution



- Enables more detail at longer distances
- Enables digital zoom-in
- Requires faster readout, ADCs, ISPs
- Requires low-power design and innovation

Kilde: Wikipedia

# Technology Trend - 3D Stacked Die



**CIS Structure**

Thanks!